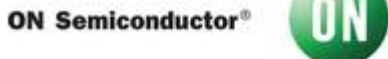











| | | |
|---|--------------------------------|--|
|  | RFP4N100 | |
| | Hersteller-Teilenummer: | RFP4N100 |
|  | Hersteller / Marke: | AMI Semiconductor / ON Semiconductor |
| | Teil der Beschreibung: | MOSFET N-CH 1KV 4.3A TO-220AB |
| | Datenblätter: |  RFP4N100.pdf |
| | RoHs Status: | Enthält Blei / RoHS nicht konform |
| | Lagerzustand: | New original, 7668 pcs Stock Available. |
| | Liefern von: | Hong Kong |
| | Versandweg: | DHL/Fedex/TNT/UPS/EMS |
| Image may be representation. See specs for product details. | | |

Spezifikationen

| | |
|--|--|
| Teilenummer | RFP4N100 |
| Hersteller | AMI Semiconductor / ON Semiconductor |
| Beschreibung | MOSFET N-CH 1KV 4.3A TO-220AB |
| Kategorie | Diskrete Halbleiterprodukte > Transistoren-FETs, |
| Teilstatus | 7668 pcs Stock |
| detaillierte Beschreibung | N-Channel 1000V 4.3A (Tc) Through Hole TO-220AB |
| Serie | - |
| Technologie | MOSFET (Metal Oxide) |
| Befestigungsart | Through Hole |
| Verpackung / Gehäuse | TO-220-3 |
| Supplier Device-Gehäuse | TO-220AB |
| Typ FET | N-Channel |
| FET-Merkmal | - |
| Drain-Source-Spannung (Vdss) | 1000V |
| Strom - Ununterbrochener Abfluss (Id) bei 25 ° C | 4.3A (Tc) |
| Rds On (Max) @ Id, Vgs | 3.5 Ohm @ 2.5A, 10V |
| VGS (th) (Max) @ Id | 4V @ 250µA |
| Gate Charge (Qg) (Max) @ Vgs | 120nC @ 20V |
| Verpackung | Tube |
| Bleifreier Status / RoHS-Status | Contains lead / RoHS non-compliant |
| Feuchtigkeitsempfindlichkeitsniveau (MSL) | 1 (Unlimited) |



















































RFP4N100 ist neu im Original. Suche RFP4N100 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie RFP4N100 AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage RFP4N100: Info@Y-IC.com

Sie können auch interessiert sein:

| | | | |
|---|---|--|--|
|  RFP4N06L F RFP4N06L F |  RFP50N05L Fairchild/ON Semiconductor MOSFET N-CH 50V 50A TO-220AB |  RFP4N100 NJS |  RFP50N06 AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 50A TO-220AB |
|  RFP4N05 VB RFP4N05 VB |  RFP4N40 VB RFP4N40 VB |  RFP45N06LE FSC RFP45N06LE FSC |  RFP4N05L F RFP4N05L F |

heiße Teile

Mehr

| | | | | |
|---|---|--|--|---|
|  RFP22N10 |  RFP2N08L |  RFP2N10L |  RFP2N10L |  RFP2N12L |
|  RFP2N20L |  RFP3055LE |  RFP3055LE |  RFP30N05 |  RFP30N06LE |
|  RFP30N06LE |  RFP30P05 |  RFP30P05 |  RFP30P06 |  RFP30P06 |
|  RFP40N10 |  RFP40N10 |  RFP40N10LE |  RFP45N02L |  RFP45N03L |
|  RFP45N06 |  RFP45N06 |  RFP45N06LE |  RFP4N05L |  RFP4N06L |
|  RFP4N100 |  RFP50N05 |  RFP50N06 |  RFP50N06 |  RFP70N03 |
|  RFP70N03 |  RFP70N03S |  RFP70N06 |  RFP70N06 |  RFP70N08 |
|  RFP8P06E |  RFP8P06LE |  RFPA5201TR13 |  RFPA5208SR |  RFPA5208TR13 |
|  RFPA5512SR |  RFPA5512TR13 |  RFPA5542TR13 |  RFPIC12C509AGT-I/SO |  RFPIC12F675F-I/SS |
|  RFPIC12F675FT-I/SS026 |  RFPIC12F675H-I/SS |  RFPK-6007 |  RFPK-6008 |  RFPK-6010 |

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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